

General Description

The SM806053 is a member of the ClockWorks® FLEX family of devices from Microchip and provides an extremely low-noise timing solution. It is based upon a unique PLL architecture that provides very-low phase noise.

The device operates from a 2.5V or 3.3V power supply.

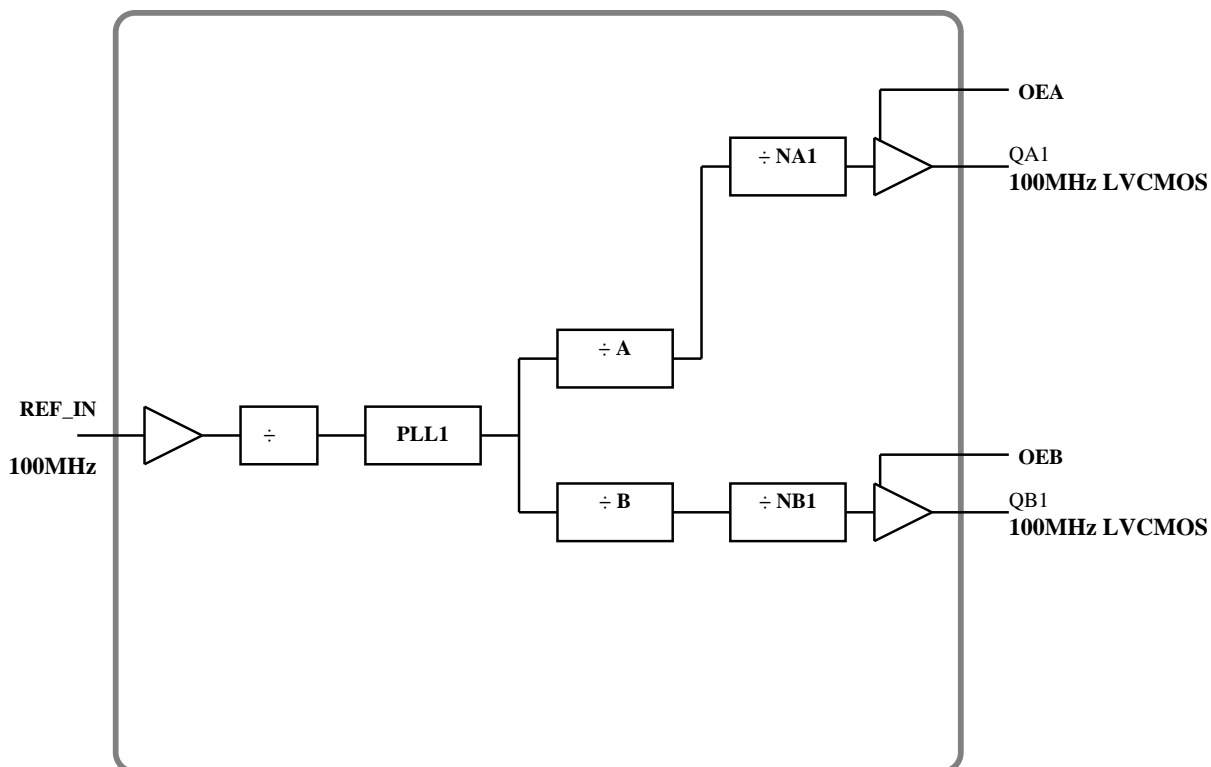
Applications

- PCI Express
- Storage

Features

- Generates 2 output clocks
- Frequency and output logic:
 - 100MHz LVCMOS x 2
- PCIe Gen 1/2/3/4/5 Compliant
- 100MHz Reference Input, DIFF
- OE on banks A and B
- Typical phase noise:
 - 78fs (Integration range: 12kHz-20MHz)
- On-chip power supply regulation for excellent board level power supply noise immunity
- No external crystal oscillator capacitors required
- 2.5V or 3.3V operating power supply
- Industrial temperature range
- 24-pin 4x4x.85mm VQFN

Block Diagram



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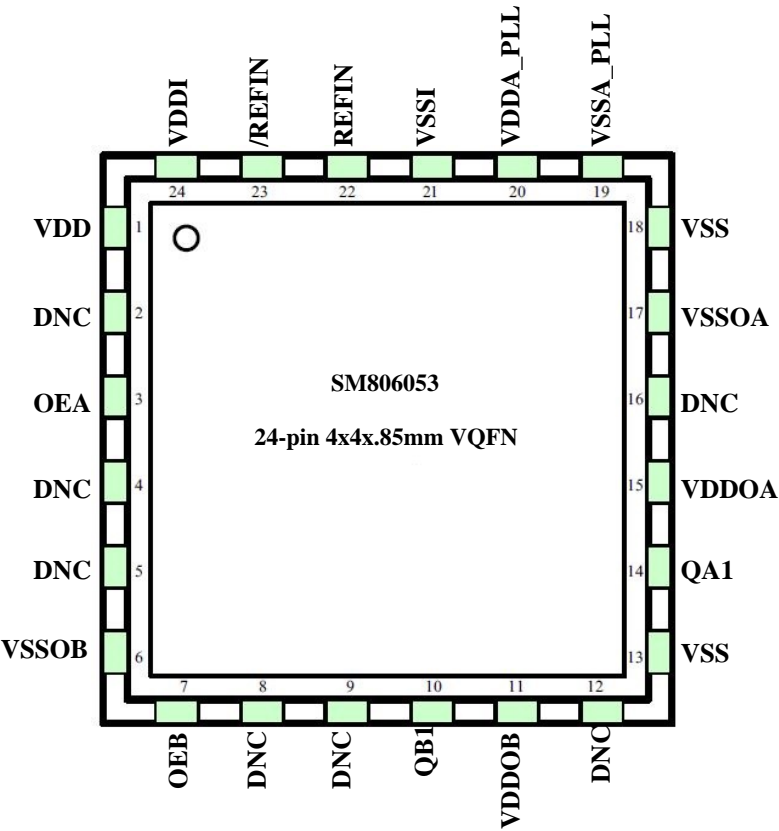
M9999-040122-A
tcghelp@microchip.com

Ordering Information

Ordering Part Number	Marking	Shipping	Ambient Temperature Range	Package
SM806053UMG	806053	Tube	-40°C to +85°C	24-pin 4x4x.85mm VQFN
SM806053UMG TR	806053	Tape and Reel	-40°C to +85°C	24-pin 4x4x.85mm VQFN

Devices are Green and RoHS compliant. Sample material may have only a partial top mark.

Pin Configuration



Pin Description

Pin Number	Pin Name	Pin Type	Pin Level	Pin Function
1	VDD	PWR		Power Supply
2, 4, 5	DNC			Do not connect anything to these pins
3	OEA	I, SE	LVC MOS	Output Enable, QA outputs disable to tri-state, 0 = Disabled, 1 = Enabled, on-chip 75k Ohms Internal Pull-Up
6	VSSOB	PWR		Ground Return Path for the Bank B Output Drivers
7	OEB	I, SE	LVC MOS	Output Enable, QB outputs disable to tri-state, 0 = Disabled, 1 = Enabled, on-chip 75k Ohms Internal Pull-Up
8	DNC			Do not connect
9	DNC			Do not connect
10, 12	QB1, DNC	O, SE	LVC MOS	Clock Output QB1 Frequency = 100MHz
11	VDDOB	PWR		Power Supply for Outputs QB
13, 18	VSS	PWR		Power Supply Ground
14, 16	QA1, DNC	O, SE	LVC MOS	Clock Output QA1 Frequency = 100MHz
15	VDDOA	PWR		Power Supply for Outputs QA
17	VSSOA	PWR		Ground Return Path for the Bank A Output Drivers
19	VSSA_PLL	PWR		Analog Power Return for PLL
20	VDDA_PLL	PWR		Analog Power Supply for PLL
21	VSSI	PWR		Ground for Reference Input Circuits and Crystal Oscillator
22, 23	REFIN, /REFIN	I, Diff	LVPECL LVDS HCSL	Reference Clock Input = 100MHz
24	VDDI	PWR		Power Supply for Reference Input Circuits and Crystal Oscillator

Absolute Maximum Ratings¹

Supply Voltage (VDD, VDDA, VDDI, VDDO).....+4.6V
 Input Voltage (VIN).....-0.50V to +4.6V
 ESD Machine Model.....200V
 ESD Human Body Model.....2kV

Operating Ratings²

Supply Voltage (VDD, VDDO)....+2.375V to +3.465V

Electrical Characteristics

Typical values are TA = 25°C, min/max across -40°C ≤ TA ≤ +85°C, unless otherwise noted.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
VDD, VDDO	Supply Voltage	2.5V Operation 3.3V Operation	2.375 3.135	2.5 3.3	2.625 3.465	V
VDDI	Analog & I/O Supply		2.375		3.465	V
VDDA	PLL Core		2.375		3.465	V
IDDA	PLL Core Current Consumption				60	mA
IDDI	Analog & I/O Current				20	mA
IDDO	Output Stage Current Consumption	Per output bank, unloaded			70	mA
IDD	SPI and Miscellaneous Logic				8	mA

REF_IN DC Electrical Characteristics

VDD = 3.3V ±5% or 2.5V ±5%, TA = -40°C to +85°C

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
Vcmr	Input Common Mode Voltage		0.3		VDD - 0.3	V
Vswing	Input Voltage Swing		0.2			VPP

Notes:

1. Exceeding the absolute maximum ratings may damage the device.
2. The device is not guaranteed to function outside its operating ratings.

LVC MOS DC Electrical Characteristics

VDDcore= VDD = VDDO = 3.3V $\pm 5\%$ or 2.5V $\pm 5\%$, TA = -40°C to +85°C, unless otherwise noted.
RL = 50 Ohms to VDDO/2.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
VOH	Output High Voltage	Highest drive (default)	VDD - 0.8			V
VOL	Output Low Voltage				0.5	V
VIH	Input High Voltage		VDD - 0.7		VDD + 0.3	V
VIL	Input Low Voltage		VSS - 0.3		0.3 x VDD	V
IIH	Input High Current	VDD = VIN = 3.465V			5	μA
IIL	Input Low Current	VDD = 3.465V, VIN = 0V	-150			μA

AC Electrical Characteristics

VDD = VDDO½ = 3.3V ±5% or 2.5V ±5%

VDD = 3.3V ±5%, VDDO½ = 3.3V ±5% or 2.5V ±5%

TA = -40°C to +85°C

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
FIN	Input Frequency	Reference Input		100		MHz
FOUT	Output Frequency	LVC MOS		100 x 2		MHz
TR/TF	Output Rise/Fall time ³	LVC MOS ouput (default drive)	100	200	400	ps
ODC	Output Duty Cycle	<400MHz output frequencies	48	50	52	%
Tpd	Input-to-Input Propagation Delay	ZDB mode Generator/Bypass mode	-100	4	100	ps ns
Tskew	Output-to-Output Skew	Notes 4, 5 Same output bank			50	ps
Tlock	PLL Lock Time			5	20	ms
Tjit(Ø)	RMS Phase Noise	Notes 6, 7 Integration range (12kHz-20MHz)		78		fs

Temperature Specifications

Parameter	Sym.	Min.	Typ.	Max.	Units	Conditions
Temperature Ranges						
Ambient Temperature Range	Ta	-40		+85	°C	
Lead Temperature				+260	°C	Soldering, 20s
Case Temperature				+115	°C	
Storage Temperature Range	Ts	-65		+150	°C	
Package Thermal Resistances (Note 8)						
Junction Thermal Resistance, 4 x 4 VQFN-24Ld	Tja		25		°C/W	Still-Air

Notes:

- See Figure 'All Outputs Rise/Fall Time'
- Output-to-output skew is defined as skew between outputs at the same supply voltage and with equal load conditions. It is measured at the output differential crossing points.
- Output-to-output skew is only defined for outputs in the same PLL bank [A:B, C:D] with the same output logic type setting.
- All phase noise measurements were taken with an Agilent 5052B phase noise system.
- Reference frequency generated using R+S SMA100A (option 02). When using an external reference input, use a low phase noise source as the phase noise will follow the input source phase noise up to about 1MHz.
- Package thermal resistance assumes the exposed pad is soldered (or equivalent) to the device's most negative potential on the PCB.

Application Information

Input Reference

When operating with a crystal input reference, do not apply a switching signal to REF_IN.

Output Traces

Design the traces for the output signals according to the output logic requirements. If LVCMOS is unterminated, add a 30 Ohms resistor in series with the output, as close as possible to the output pin and start a 50 Ohms trace on the other side of the resistor.

For differential traces you can either use a differential design or two separate 50 Ohms traces. For EMI reasons, it is better to use a balanced differential design.

LVDS can be AC coupled or DC coupled to its termination.

Power Supply Filtering Recommendations



Figure 1. Recommended Power Supply Filtering

- Use the power supply filtering shown in above figure for VDD, VDDA_PLL, VDDI.
- Connect the VDDO pins directly to the VDD power plane.
- Connect all VSS pins directly to the ground power plane.
- Recommended ferrite bead properties are 80 Ohms to 240 Ohms @100MHz impedance and >250mA saturation current.
- To improve power supply filtering beyond what a ferrite bead can provide, Microchip's Ripple Blocker™ provides a solution. MIC94300 or MIC94310 are recommended parts. The filter circuit with Ripple Blocker is shown in below figure and can be used for any of the above VDD sections.
- Do not use Y5V or Z5U capacitors.



Figure 2. Power Supply Filtering with Ripple Blocker

Timing Diagrams



Figure 3. Duty Cycle Timing



Figure 4. All Outputs Rise/Fall Time

RMS Phase/Noise/Jitter



Figure 5. RMS Phase/Noise/Jitter

Output Termination

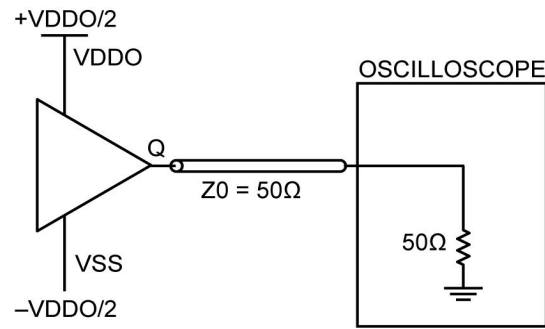
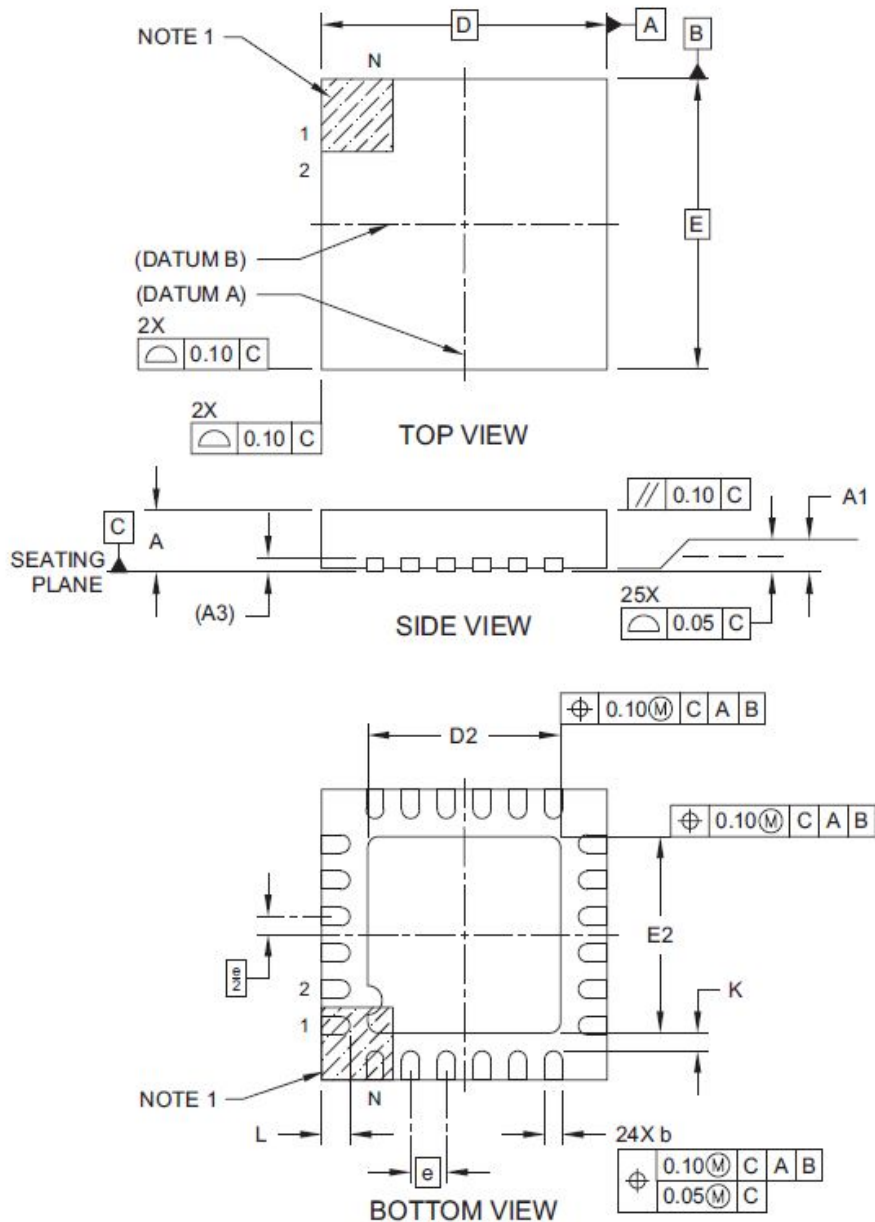


Figure 6. LVC MOS Output Load and Test Circuit

Packaging Information

24-Lead Very Thin Plastic Quad Flat, No Lead Package (9KX) - 4x4 mm Body [VQFN]
With 2.7x2.7 mm Exposed Pad

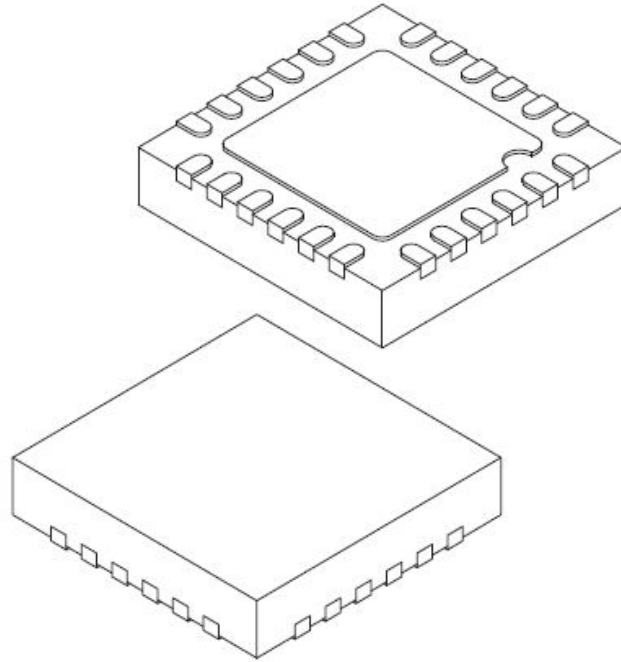
Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



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24-Lead Very Thin Plastic Quad Flat, No Lead Package (9KX) - 4x4 mm Body [VQFN] With 2.7x2.7 mm Exposed Pad

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Terminals	N	24		
Pitch	e	0.50 BSC		
Overall Height	A	0.80	0.85	0.90
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3	0.20 REF		
Overall Length	D	4.00 BSC		
Exposed Pad Length	D2	2.60	2.70	2.80
Overall Width	E	4.00 BSC		
Exposed Pad Width	E2	2.60	2.70	2.80
Terminal Width	b	0.18	0.25	0.30
Terminal Length	L	0.35	0.40	0.45
Terminal-to-Exposed-Pad	K	0.25 REF		

Notes:

- Pin 1 visual index feature may vary, but must be located within the hatched area.
- Package is saw singulated
- Dimensioning and tolerancing per ASME Y14.5M

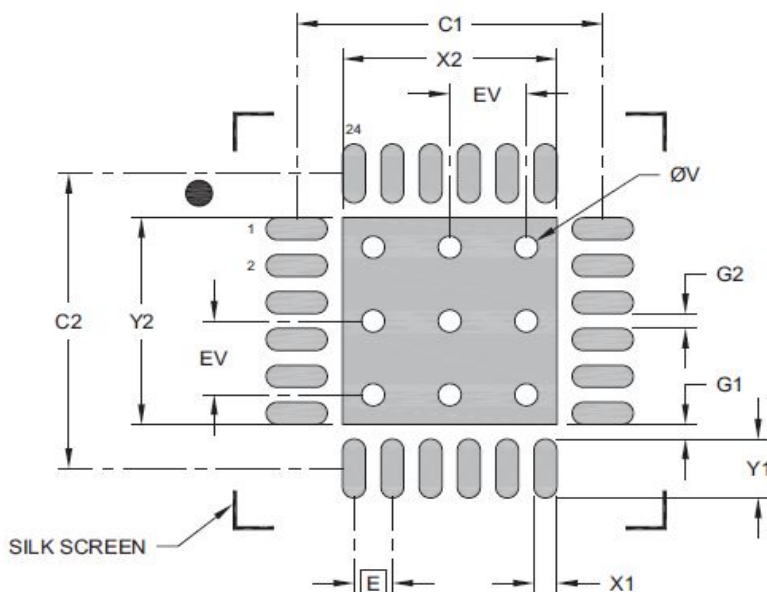
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

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24-Lead Very Thin Plastic Quad Flat, No Lead Package (9KX) - 4x4 mm Body [VQFN] With 2.7x2.7 mm Exposed Pad

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

		Units	MILLIMETERS		
Dimension Limits			MIN	NOM	MAX
Contact Pitch	E			0.50 BSC	
Optional Center Pad Width	X2				2.80
Optional Center Pad Length	Y2				2.80
Contact Pad Spacing	C1			4.00	
Contact Pad Spacing	C2			4.00	
Contact Pad Width (X24)	X1				0.30
Contact Pad Length (X24)	Y1				0.80
Contact Pad to Center Pad (X24)	G1	0.20			
Contact Pad to Contact Pad (X20)	G2	0.20			
Thermal Via Diameter	V			0.30	
Thermal Via Pitch	EV			1.00	

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M
BSC: Basic Dimension. Theoretically exact value shown without tolerances.
2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

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